Temperature-dependent break-down of disorder-induced localization

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We study the temperature-dependent transport of interacting fermions through a disordered tight-binding chain in the presence of a thermal bath of temperature T. This model describes electronic systems coupled to phonons and can also be realized with ultracold fermionic atoms immersed in a Bose gas. By employing two different methods, quantum-jump Monte-Carlo simulations and mean-field theory, we find different regimes with respect to temperature. For low temperatures, we encounter a (many-body) localized regime, where the transport is temperature-independent and decreases exponentially with the system size. Above a system-size dependent threshold temperature, a bath-assisted temperature-dependent conductivity σ is found. It is described by Mott's law for variable-range hopping, $\sigma \sim \exp(-\sqrt{T_0/T})$. Weak repulsive (attractive) interactions are found to enhance (lower) T_0 .